

Date: - 22 Sept, 2006

Data Sheet Issue:- 1

Rectifier Diode Types W4534N#020 to W4534N#060

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	200–600	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	300–700	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
I _{F(AV)M}	Maximum average forward current, T _{sink} =55°C, (note 2)	4543	Α
$I_{F(AV)M}$	Maximum average forward current. T _{sink} =100°C, (note 2)	3400	Α
$I_{F(AV)M}$	Maximum average forward current. T _{sink} =100°C, (note 3)	1999	Α
I _{F(RMS)}	Nominal RMS forward current, T _{sink} =25°C, (note 2)	8200	Α
I _{F(d.c.)}	D.C. forward current, T _{sink} =25°C, (note 4)	6727	Α
I _{FSM}	Peak non-repetitive surge t _p =10ms, V _m =60%V _{RRM} , (note 5)	40	kA
I _{FSM2}	Peak non-repetitive surge t _p =10ms, V _m ≤10V, (note 5)	44	kA
I ² t	I²t capacity for fusing t _p =10ms, V _m =60%V _{RRM} , (note 5)	8.00×10 ⁶	A ² s
I ² t	I²t capacity for fusing t _p =10ms, V _m ≤10V, (note 5)	9.68×10 ⁶	A ² s
T _{j op}	Operating temperature range	-40 to +190	°C
T_{stg}	Storage temperature range	-40 to +190	°C

Notes:-

- 1) De-rating factor of 0.13% per $^{\circ}$ C is applicable for T_{j} below 25 $^{\circ}$ C.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Single side cooled, single phase; 50Hz, 180° half-sinewave.
- 4) Double side cooled.
- 5) Half-sinewave, 190°C T_i initial.



Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V_{FM}	Maximum peak forward voltage	-	-	1.10	I _{FM} =6400A	V
V_{FM}	Maximum peak forward voltage	-	-	1.38	I _{FM} =13630A	V
V_{T0}	Threshold voltage	-	-	0.765		V
r _T	Slope resistance	-	-	0.052		mΩ
I _{RRM}	Peak reverse current	-	-	50	Rated V _{RRM}	mA
Q _{rr}	Recovered charge	-	1010	-		μC
Q_{ra}	Recovered charge, 50% chord	-	880	900	I _{FM} =2000A, t _p =1000μs, di/dt=10A/μs,	μC
I _{rm}	Reverse recovery current	-	110	-	V _r =50V	Α
t _{rr}	Reverse recovery time, 50% chord	-	16	-		μs
0	Th	-	-	0.022	Double side cooled	K/W
R_{thJK}	Thermal resistance, junction to heatsink	-	-	0.044	Single side cooled	K/W
F	Mounting force	19	-	26	Note 2	kN
W_t	Weight	-	510	-		g

Notes:-

- 1) Unless otherwise indicated $T_j=190$ °C.
- 2) For other clamp forces, please consult factory.



Notes on Ratings and Characteristics

1.0 Voltage Grade Table

Voltage Grade	V _{RRM} V	V _{RSM} V	V _R DC V
02	200	300	140
04	400	500	260
06	600	700	420

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_j below 25°C.

4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

5.0 Computer Modelling Parameters

5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{{V_{T0}}^2 + 4 \cdot f\!f^2 \cdot r_T \cdot W_{AV}}}{2 \cdot f\!f^2 \cdot r_T} \qquad \qquad W_{AV} = \frac{\Delta T}{R_{th}}$$
 and:
$$\Delta T = T_{j\,\text{max}} - T_K$$

Where V_{T0} =0.765V, r_{T} =0.052 $m\Omega$,

 R_{th} = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance					
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.	
Square wave Double Side Cooled	0.0285	0.0255	0.0240	0.0220	
Square wave Single Side Cooled	0.0513	0.0484	0.0469	0.0440	
Sine wave Double Side Cooled	0.0257	0.0233	0.022		
Sine wave Single Side Cooled	0.0482	0.0463	0.044		

Form Factors					
Conduction Angle 6 phase (60°) 3 phase (120°) ½ wave (180°) d.c.					
Square wave	2.449	1.732	1.414	1	
Sine wave	2.778	1.879	1.57		



5.2 Calculating V_F using ABCD Coefficients

The on-state characteristic I_F vs. V_F, on page 6 is represented in two ways;

- (i) the well established V_{T0} and r_T tangent used for rating purposes and
- (ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

	25°C Coefficients		190°C Coefficients
Α	0.6210661	Α	0.3613024
В	0.03147985	В	0.02842117
С	2.530387×10 ⁻⁵	С	1.731433×10 ⁻⁵
D	1.27501×10 ⁻³	D	3.803441×10 ⁻³



5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{\frac{-t}{\tau_p}}\right)$$

Where p = 1 to n, n is the number of terms in the series and:

t = Duration of heating pulse in seconds.

 r_{+} = Thermal resistance at time t.

 r_p = Amplitude of p_{th} term.

 τ_p = Time Constant of r_{th} term.

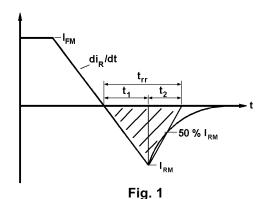
The coefficients for this device are shown in the tables below:

D.C. Single Side Cooled						
Term	Term 1 2 3 4 5					
r_p	0.0291698	4.295845×10 ⁻³	7.57109×10 ⁻³	2.195801×10 ⁻³	1.628753×10 ⁻³	
$ au_{\mathcal{P}}$	5.67822	1.123602	0.1407857	0.014381914	1.272749×10 ⁻³	

D.C. Double Side Cooled							
Term	n 1 2 3 4						
r_p	0.01177146	6.485814×10 ⁻³	2.471007×10 ⁻³	1.607109×10 ⁻³			
$ au_{\mathcal{P}}$	0.9495346	0.1337950	0.01636628	1.255571×10 ⁻³			

6.0 Reverse Recovery Ratings

(i) Qra is based on 50% Irm chord as shown in Fig. 1



(ii) Q_{rr} is based on a 150μs integration time i.e.

$$Q_{rr} = \int_{0}^{150 \, \mu s} i_{rr}.dt$$

(iii)
$$K Factor = \frac{t_1}{t_2}$$

Curves

Figure 1 – Forward characteristics of limit device

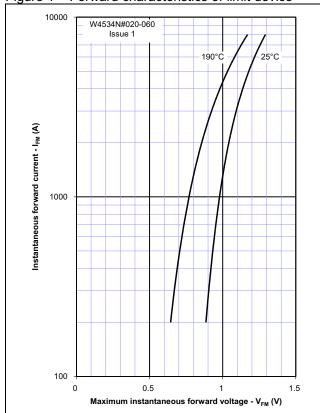


Figure 2 – Transient thermal impedance

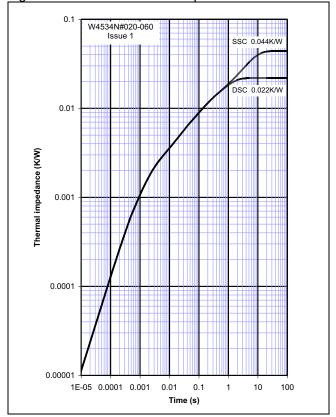


Figure 3 – Maximum surge rating

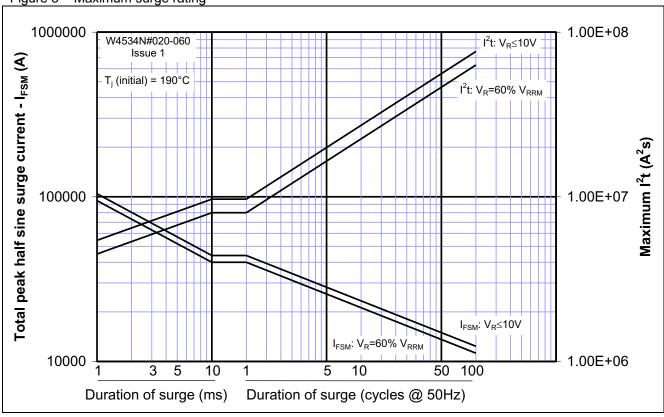


Figure 4 - Total recovered charge, Q_{rr}

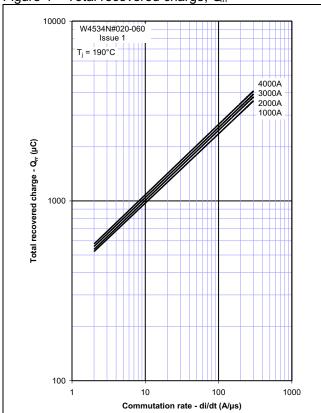
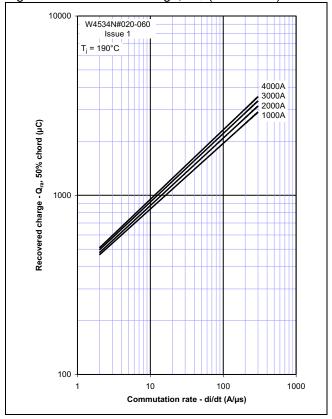


Figure 5 – Recovered charge, Q_{ra} (50% chord)



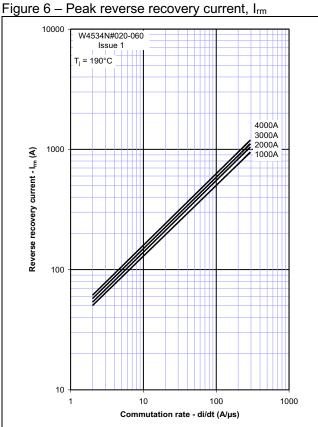


Figure 7 – Maximum recovery time, t_{rr} (50% chord)

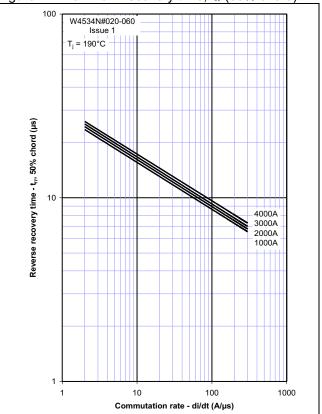


Figure 8 – Forward current vs. Power dissipation – Double Side Cooled

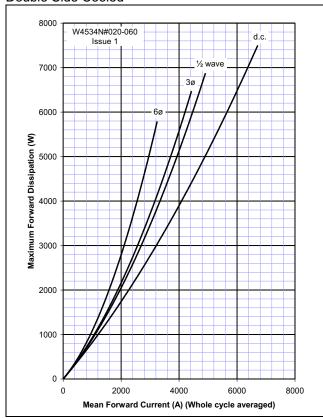


Figure 10 – Forward current vs. Power dissipation – Single Side Cooled

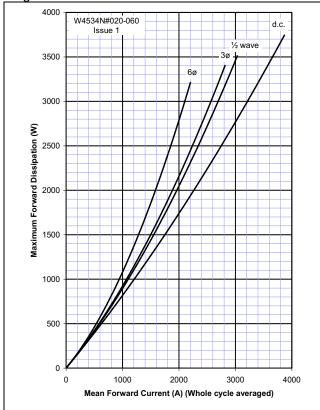


Figure 9 – Forward current vs. Heatsink temperature – Double Side Cooled

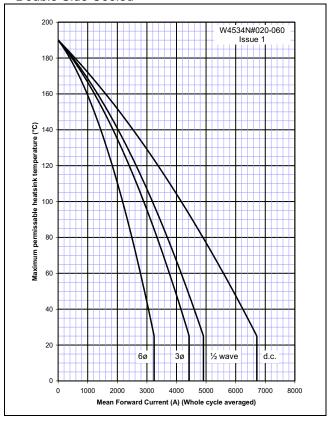
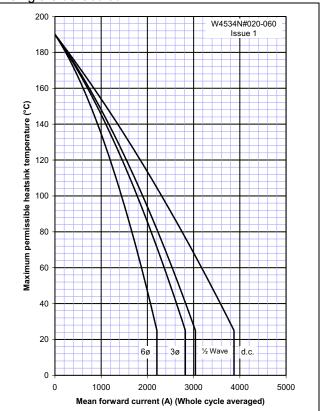
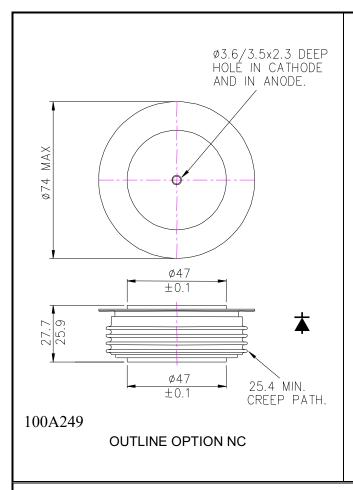
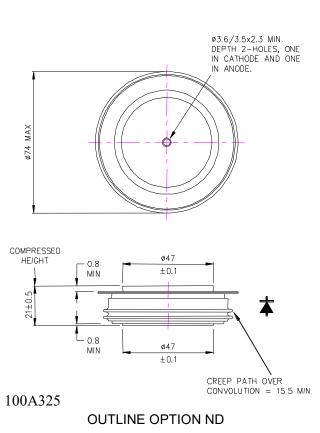


Figure 11 – Forward current vs. Heatsink temperature – Single Side Cooled



Outline Drawing & Ordering Information





ORDER	ING INFORMATION	(Please quote 10 digit code as below)		
W4534 ♦♦		**	0	
Fixed Type Code	Outline code NC = 26mm Clamp height ND = 21mm Clamp height	Voltage code V _{RRM} /100 02 – 06	Fixed code	

Typical order code: W4534NC020 – 200V V_{RRM}, 26mm clamp height capsule.

IXYS Semiconductor GmbH

Edisonstraße 15 D-68623 Lampertheim Tel: +49 6206 503-0 Fax: +49 6206 503-627

Fax: +49 6206 503-627 E-mail: <u>marcom@ixys.de</u>

IXYS Corporation

3540 Bassett Street Santa Clara CA 95054 USA Tel: +1 (408) 982 0700 Fax: +1 (408) 496 0670

Fax: +1 (408) 496 0670 E-mail: <u>sales@ixvs.net</u>

WESTCODE An LIXYS Company

www.westcode.com

www.ixys.net

Westcode Semiconductors Ltd

Langley Park Way, Langley Park, Chippenham, Wiltshire, SN15 1GE. Tel: +44 (0)1249 444524 Fax: +44 (0)1249 659448

E-mail: WSL.sales@westcode.com

Westcode Semiconductors Inc

3270 Cherry Avenue Long Beach CA 90807 USA Tel: +1 (562) 595 6971 Fax: +1 (562) 595 8182

E-mail: WSI.sales@westcode.com

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